

## EE247

### Lecture 7

- Automatic on-chip filter tuning (continued from last lecture)
  - Continuous tuning (continued)
    - DC tuning of resistive timing element
  - Periodic digitally assisted filter tuning
    - Systems where filter is followed by ADC & DSP, existing hardware can be used to periodically update filter freq. response
- Continuous-time filter design considerations
  - Monolithic highpass filters
  - Active bandpass filter design
    - Lowpass to bandpass transformation
    - Example: 6<sup>th</sup> order bandpass filter
    - Gm-C bandpass filter using simple diff. pair
  - Various Gm-C filter implementations

## Summary last lecture

- Continuous-time filters (continued)
  - Gm-C filters
- Frequency tuning for continuous-time filters
  - Trimming via fuses or laser
  - Automatic on-chip filter tuning
    - Continuous tuning
      - Utilizing VCF built with replica integrators
      - Use of VCO built with replica integrators
      - Replica single integrator in a feedback loop locked to a reference frequency

## DC Tuning of Resistive Timing Element

Tuning circuit  $Gm \rightarrow$  replica of  $Gm$  used in filter

$R_{ext}$  used to lock  $Gm$  to accurate off-chip  $R$

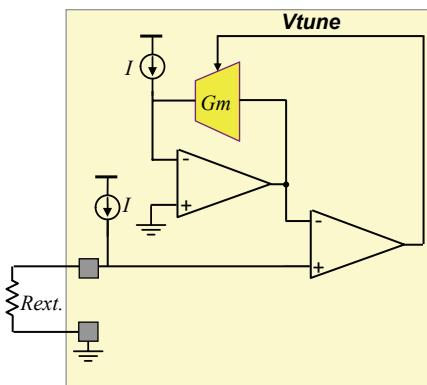
Feedback forces:

$I \times R_{ext}$  @  $Gm$ -cell input

Current flowing in  $Gm$ -Cell  $\rightarrow I$   
 $Gm = I/R_{ext}$

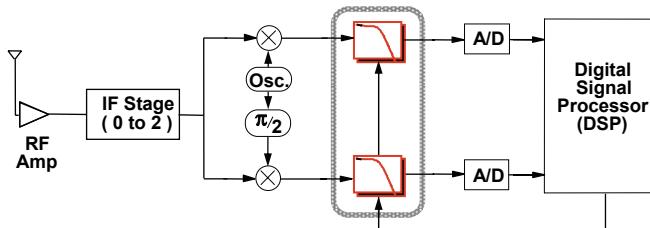
Issues with DC offset

Account for capacitor variations in this  $Gm$ -C implementation by trimming  $C$  in the factory



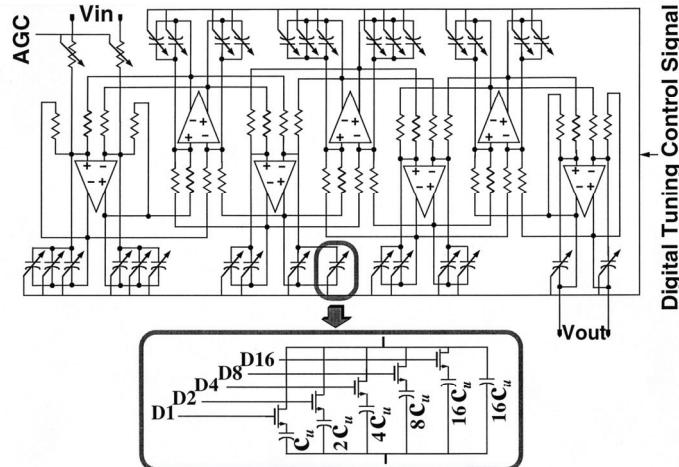
Ref: C. Laber and P.R. Gray, "A 20MHz 6th Order BiCMOS Parasitic Insensitive Continuous-time Filter and Second Order Equalizer Optimized for Disk Drive Read Channels," *IEEE Journal of Solid State Circuits*, Vol. 28, pp. 462-470, April 1993

## Digitally Assisted Frequency Tuning Example: Wireless Receiver Baseband Filters



- Systems where filter is followed by ADC & DSP
  - Take advantage of existing digital signal processor capabilities to periodically test & if needed update the filter critical frequency
  - Filter tuned only at the outset of each data transmission session (off-line/periodic tuning) – can be fine tuned during times data is not transmitted or received

### Example: Seventh Order Tunable Low-Pass OpAmp-RC Filter



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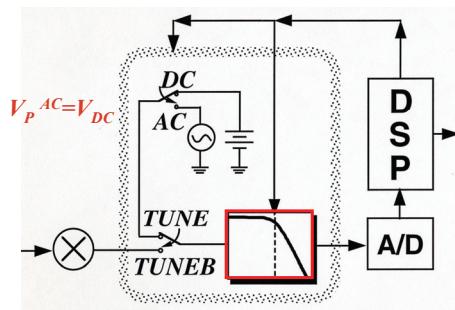
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### Digitally Assisted Filter Tuning Concept

#### Assumptions:

- System allows a period of time for the filter to undergo tuning (e.g. for a wireless transceiver during idle periods)
- An AC (e.g. a sinusoid) signal can be generated on-chip whose amplitude is a function of an on-chip DC voltage
  - AC signal generator outputs a sinusoid with peak voltage equal to the DC signal source
  - AC Signal Power =  $1/2$  DC signal power @ the input of the filter

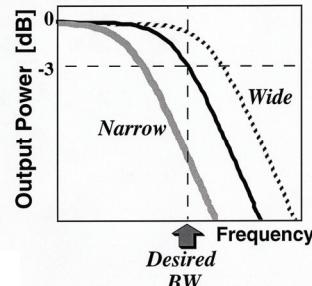
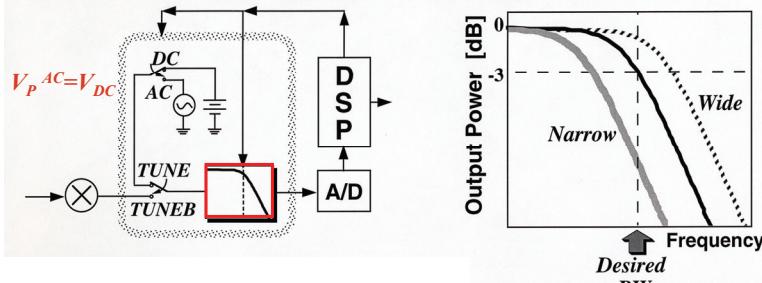


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## Digitally Assisted Filter Tuning Concept



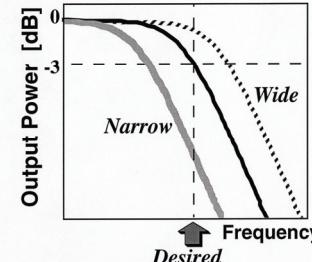
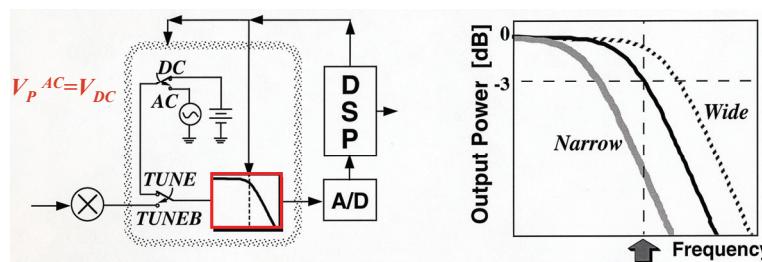
AC signal @ a frequency on the roll-off of the desired filter frequency response (e.g. -3dB frequency)  $V_{AC} = V_{DC} \times \sin(2\pi f_{-3dB} t)$

Provision can be made → during the tuning cycle, the input of the filter is disconnected from the previous stage (e.g. mixer) and connected to:

1. DC source
2. AC source

under the control of the DSP

## Digitally Assisted Filter Tuning Concept



### Tuning Cycle:

Connect the filter input to DC source

DSP measures the DC power level

Connect the filter input to AC source (freq. → desired -3dB freq.)

DSP measures the AC signal power level

If DC = 4\*AC

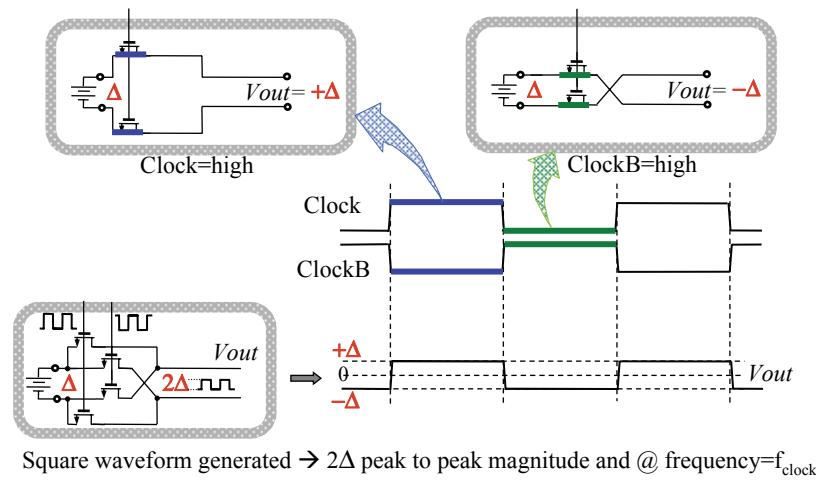
Then filter is tuned

Else If DC > 4\*AC

Then widen the filter bandwidth & repeat

Else narrow the filter bandwidth & repeat

## Practical Implementation of Frequency Tuning AC Signal Generation From DC Source

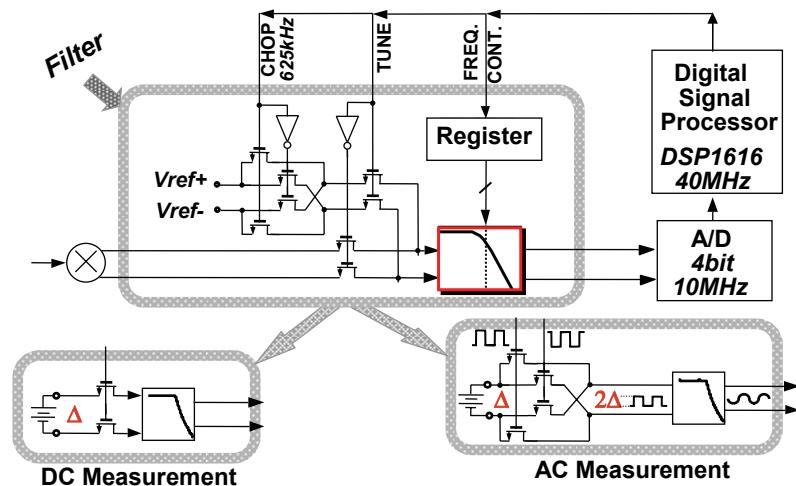


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## Practical Implementation of Frequency Tuning

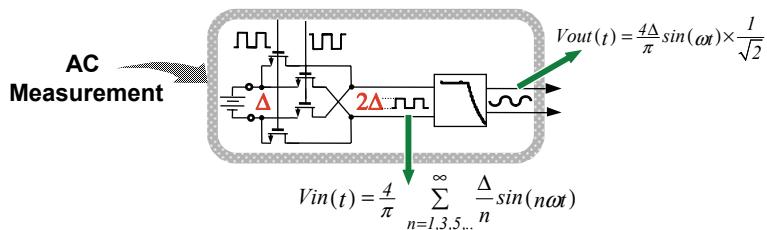


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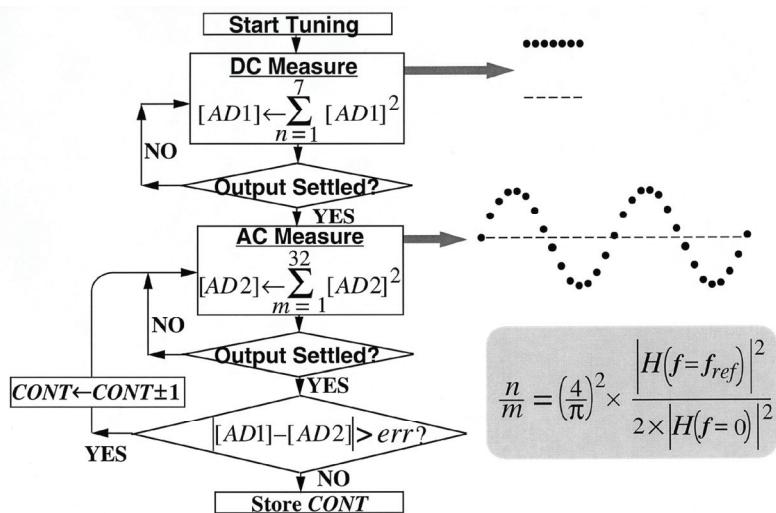
## Practical Implementation of Frequency Tuning Effect of Using a Square Waveform



- Input signal chosen to be a square wave due to ease of generation
- Filter input signal comprises a sinusoidal waveform @ the fundamental frequency + its odd harmonics:

*Key Point: The filter itself attenuates unwanted odd harmonics  
→ Inaccuracy incurred by the harmonics negligible*

## Simplified Frequency Tuning Flowchart

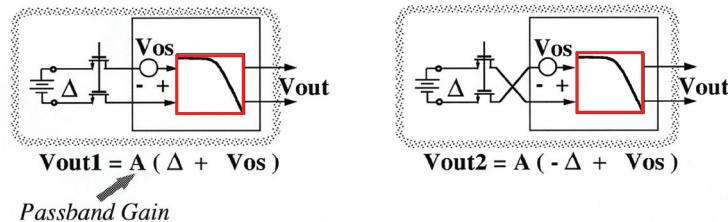


## Digitally Assisted Offset Compensation

In cases where the filter DC offset cause significant error in tuning  
(i.e. high passband gain)

- Offset compensation needed:

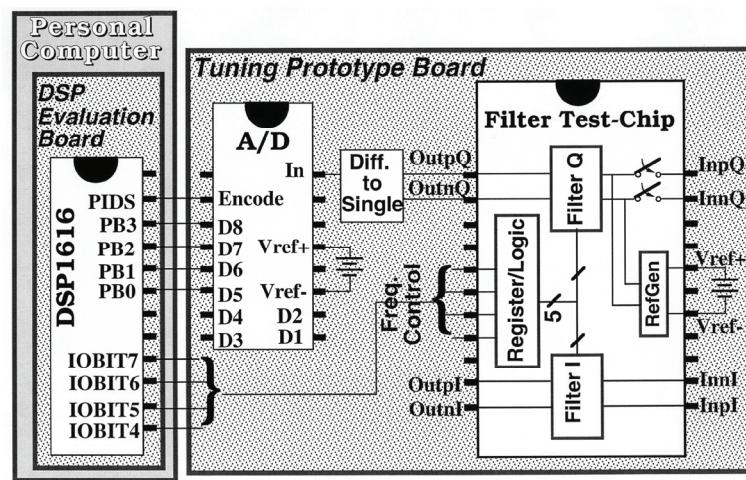
⇒ DC measurement performed in two steps:



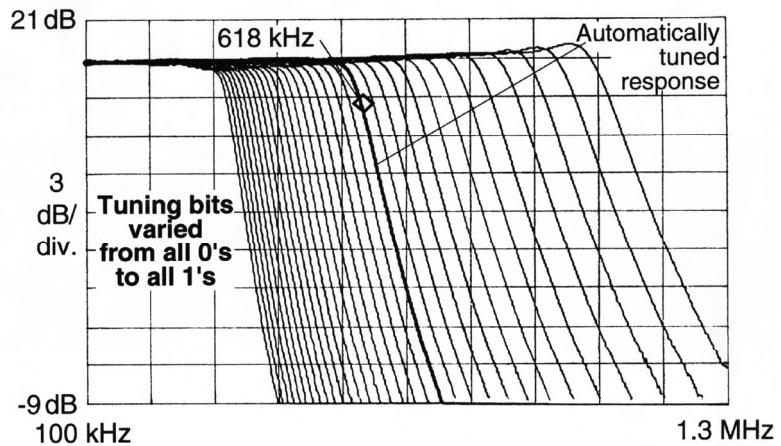
⇒ DSP extracts: Offset component →  $1/2(V_{out1} + V_{out2}) = A \cdot V_{os}$   
DC component →  $1/2(V_{out1} - V_{out2}) = A \cdot \Delta$

⇒ DSP subtracts  $V_{os}$  from all subsequent AC measurement

## Filter Tuning Prototype Diagram



## Measured Frequency Response



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## Measured Tuning Characteristics

Tunable frequency range (nom. process)	370kHz to 1.1M
Variations due to process	±50%
I/Q bandwidth imbalance	0.1%
Tuning resolution (620kHz frequency range)	<i>Measured</i> 3.8% <i>Expected</i> 2-5%
Tuning time	<i>Coarse+Fine</i> max. 800μsec <i>Fine only</i> min. 50μsec
Memory space required for tuning routine	250 byte

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## Off-line Digitally Assisted Tuning

- Advantages:
  - No reference signal feedthrough since tuning does not take place during data transmission (off-line)
  - Minimal additional hardware
  - Small amount of programming
- Disadvantages:
  - If acute temperature change during data transmission, filter may slip out of tune!
    - Can add fine tuning cycles during periods of data is not transmitted or received

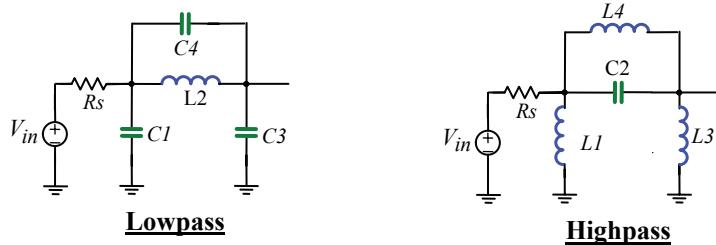
Ref: H. Khorramabadi, M. Tarsia and N.Woo, "Baseband Filters for IS-95 CDMA Receiver Applications Featuring Digital Automatic Frequency Tuning," *1996 International Solid State Circuits Conference*, pp. 172-173.

## Summary: Continuous-Time Filter Frequency Tuning

- Trimming
  - Expensive & does not account for temperature and supply etc... variations
- Automatic frequency tuning
  - Continuous tuning
    - Master VCF used in tuning loop, same tuning signal used to tune the slave (main) filter
      - Tuning quite accurate
      - Issue → reference signal feedthrough to the filter output
    - Master VCO used in tuning loop
      - Design of reliable & stable VCO challenging
      - Issue → reference signal feedthrough
    - Single integrator in negative feedback loop forces time-constant to be a function of accurate clock frequency
      - More flexibility in choice of reference frequency → less feedthrough issues
    - DC locking of a replica of the integrator to an external resistor
      - DC offset issues & does not account for integrating capacitor variations
  - Periodic digitally assisted tuning
    - Requires digital capability + minimal additional hardware
    - Advantage of no reference signal feedthrough since tuning performed off-line

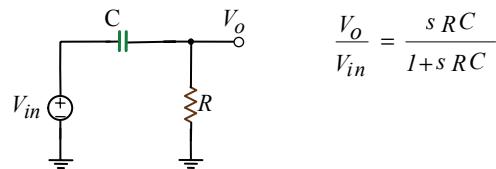
## RLC Highpass Filters

- Any RLC lowpass can be converted to highpass by:
  - Replacing all Cs by Ls and  $L_{Norm}^{HP} = 1/C_{Norm}^{LP}$
  - Replacing all Ls by Cs and  $C_{Norm}^{HP} = 1/L_{Norm}^{LP}$
  - $L^{HP} = L_r / C_{Norm}^{LP}$ ,  $C^{HP} = C_r / L_{Norm}^{LP}$  where  $L_r = R_r/\omega_r$  and  $C_r = 1/(R_r\omega_r)$



## Integrator Based High-Pass Filters 1st Order

- Conversion of simple high-pass RC filter to integrator-based type by using signal flowgraph technique



### 1<sup>st</sup> Order Integrator Based High-Pass Filter Signal Flowgraph

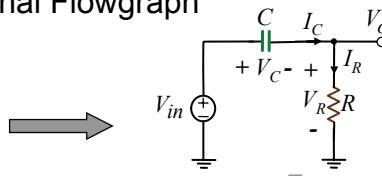
$$V_R = V_{in} - V_C$$

$$V_C = I_C \times \frac{1}{sC}$$

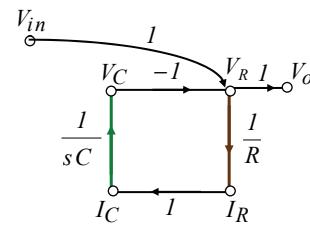
$$V_o = V_R$$

$$I_R = V_R \times \frac{1}{R}$$

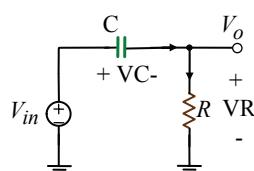
$$I_C = I_R$$



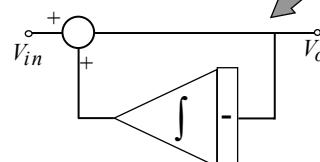
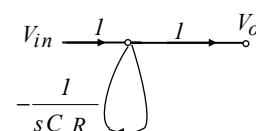
SFG



### 1<sup>st</sup> Order Integrator Based High-Pass Filter SGF



SGF



Note: Addition of an integrator in the feedback path → High pass frequency shaping

## Addition of Integrator in Feedback Path

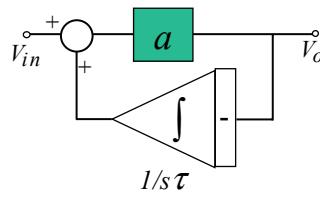
Let us assume flat gain in forward path ( $a$ )

Effect of addition of an integrator in the feedback path:

$$\frac{V_o}{V_{in}} = \frac{a}{1+af}$$

$$\frac{V_o}{V_{in}} = \frac{a}{1+a/s\tau} = \frac{s\tau}{1+s\tau/a}$$

$$\rightarrow \text{zero@DC} \quad \& \quad \text{pole@ } \omega_{pole} = -\frac{a}{\tau} = -a \times \omega_0^{intg}$$



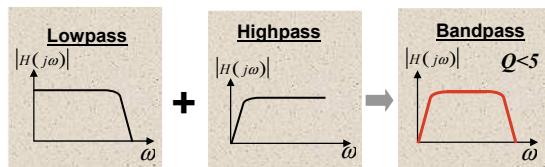
Note: For large forward path gain,  $a$ , can implement high pass function with high corner frequency

Addition of an integrator in the feedback path  $\rightarrow$  zero @ DC + pole @  $a\omega_0^{intg}$

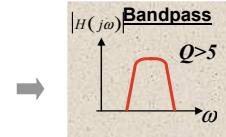
This technique used for offset cancellation in systems where the low frequency content is not important and thus disposable

## Bandpass Filters

- Bandpass filters  $\rightarrow$  two cases:
  - 1- Low  $Q$  or wideband ( $Q < 5$ )
  $\rightarrow$  Combination of lowpass & highpass

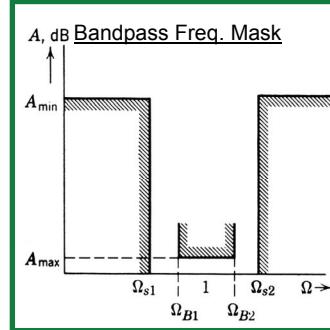
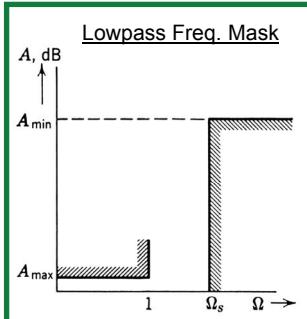


- 2- High  $Q$  or narrow-band ( $Q > 5$ )
  $\rightarrow$  Direct implementation



## Narrow-Band Bandpass Filters Direct Implementation

- Narrow-band BP filters → Design based on lowpass prototype
- Same tables used for LPFs are also used for BPFs



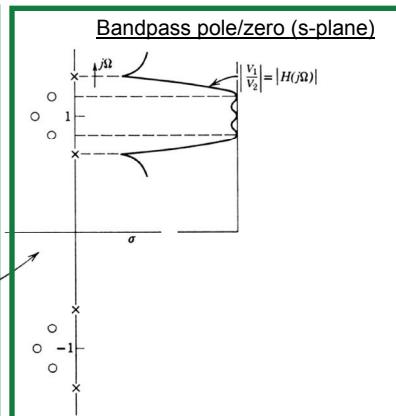
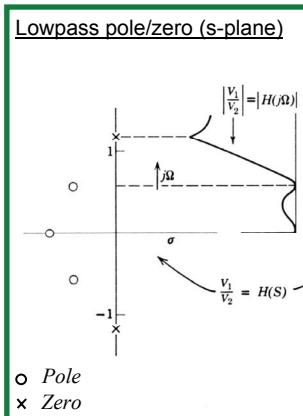
$$s \Rightarrow Q \times \left[ \frac{s}{\omega_c} + \frac{\omega_c}{s} \right] \quad \frac{\Omega_S}{\Omega_c} \Rightarrow \frac{\Omega_{S2} - \Omega_{S1}}{\Omega_{B2} - \Omega_{B1}}$$

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## Lowpass to Bandpass Transformation



From: Zverev, *Handbook of filter synthesis*, Wiley, 1967- p.156.

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## Lowpass to Bandpass Transformation Table

Lowpass RLC filter structures & tables used to derive bandpass filters

$$Q = Q_{filter}$$

From:  
Zverev,  
*Handbook of filter synthesis*,  
Wiley, 1967- p.157.

LP	BP	BP Values
		$\begin{cases} C = QC' \times \frac{1}{R_r \omega_r} \\ L = \frac{1}{QC'} \times \frac{R_r}{\omega_r} \end{cases}$
		$\begin{cases} L = QL' \times \frac{R_r}{\omega_r} \\ C = \frac{1}{QL'} \times \frac{1}{R_r \omega_r} \end{cases}$

*C' & L' are normalized LP values*

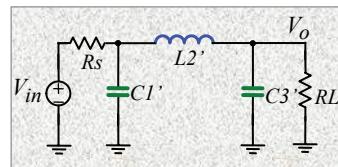
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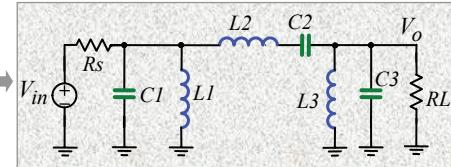
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## Lowpass to Bandpass Transformation Example: 3<sup>rd</sup> Order LPF → 6<sup>th</sup> Order BPF

Lowpass



Bandpass



- Each capacitor replaced by parallel L & C
- Each inductor replaced by series L & C

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## Lowpass to Bandpass Transformation

### Example: 3<sup>rd</sup> Order LPF $\rightarrow$ 6<sup>th</sup> Order BPF

$$C_1 = Q C_1' \times \frac{1}{R \omega_0}$$

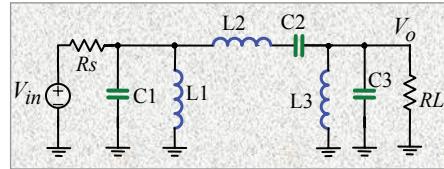
$$L_1 = \frac{1}{Q C_1'} \times \frac{R}{\omega_0}$$

$$C_2 = \frac{1}{Q L_2} \times \frac{1}{R \omega_0}$$

$$L_2 = Q L_2' \times \frac{R}{\omega_0}$$

$$C_3 = Q C_3' \times \frac{1}{R \omega_0}$$

$$L_3 = \frac{1}{Q C_3'} \times \frac{R}{\omega_0}$$



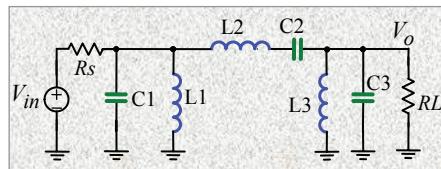
Where:

$C_1'$ ,  $L_2'$ ,  $C_3'$   $\rightarrow$  Normalized lowpass values

$Q$   $\rightarrow$  Bandpass filter quality factor

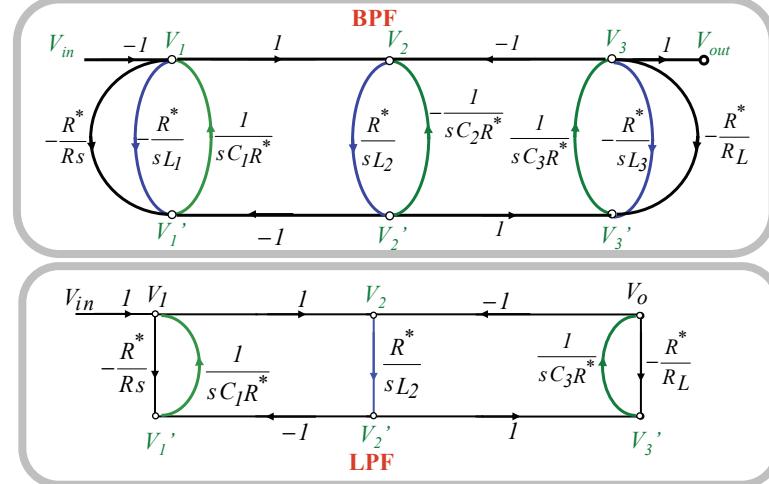
$\omega_0$   $\rightarrow$  Filter center frequency

## Lowpass to Bandpass Transformation Signal Flowgraph

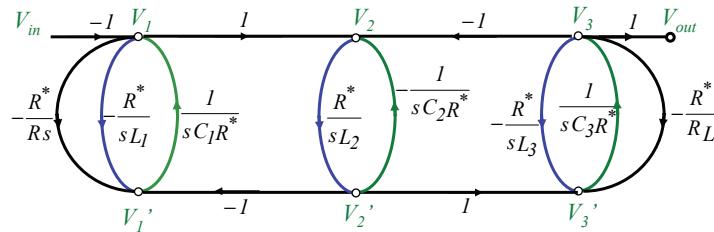


- 1- Voltages & currents named for all components
- 2- Use KCL & KVL to derive state space description
- 3- To have BMFs in the integrator form
  - Cap. voltage expressed as function of its current  $V_C = f(I_C)$
  - Ind. current as a function of its voltage  $I_L = f(V_L)$
- 4- Use state space description to draw SFG
- 5- Convert all current nodes to voltage

## Signal Flowgraph 6<sup>th</sup> Order BPF versus 3<sup>rd</sup> Order LPF



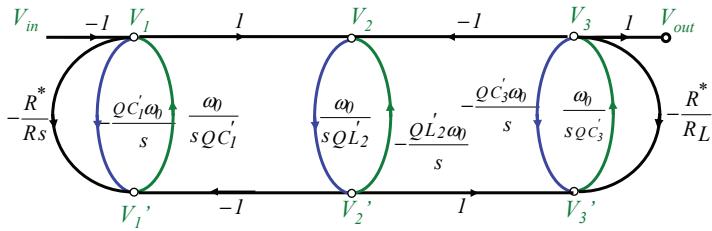
## Signal Flowgraph 6<sup>th</sup> Order Bandpass Filter



Note: each  $C & L$  in the original lowpass prototype  $\rightarrow$  replaced by a *resonator*  
 Substituting the bandpass  $L_1, C_1, \dots$  by their normalized lowpass equivalent from page 29

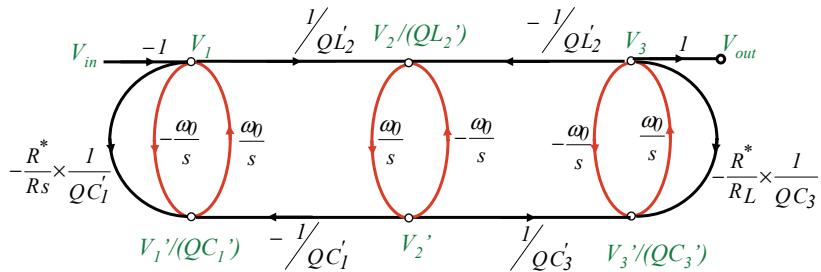
The resulting SFG is:

## Signal Flowgraph 6<sup>th</sup> Order Bandpass Filter



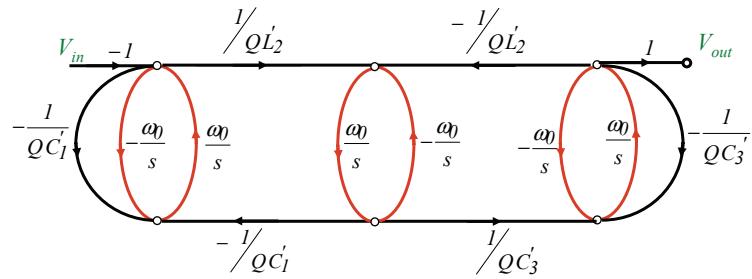
- Note the integrators → different time constants
  - Ratio of time constants for two integrator in each resonator loop  $\sim Q^2$   
→ Typically, requires high component ratios  
→ Poor matching
  - Desirable to modify SFG so that all integrators have equal time constants for optimum matching.
    - To obtain equal integrator time constant → use node scaling

## Signal Flowgraph 6<sup>th</sup> Order Bandpass Filter



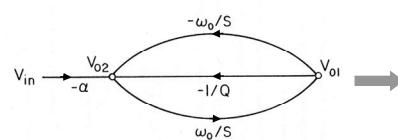
- All integrator time-constants → equal
  - To simplify implementation → choose  $R_L = R_s = R^*$

## Signal Flowgraph 6<sup>th</sup> Order Bandpass Filter



Let us try to build this bandpass filter using the simple Gm-C structure

### Second Order Gm-C Filter Using Simple Source-Couple Pair Gm-Cell

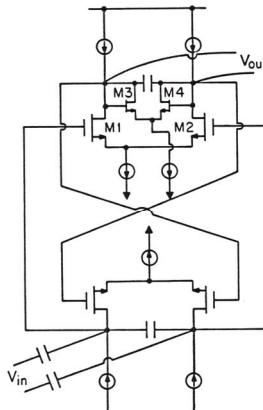


- Center frequency:

$$\omega_0 = \frac{g_m^{M1,2}}{2 \times C_{intg}}$$

- Q function of:

$$Q = \frac{g_m^{M1,2}}{g_m^{M3,4}}$$



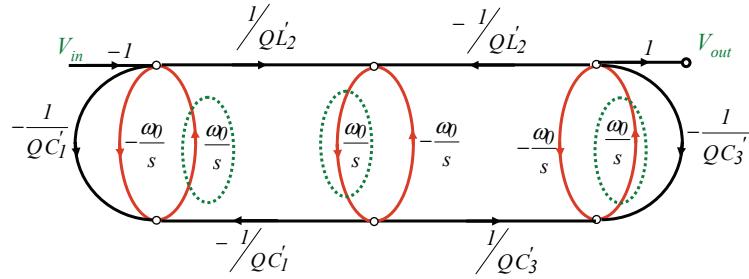
Use this structure for the 1<sup>st</sup> and the 3<sup>rd</sup> resonator

Use similar structure w/o M3, M4 for the 2<sup>nd</sup> resonator

How to couple the resonators?

## Coupling of the Resonators

### 1- Additional Set of Input Devices



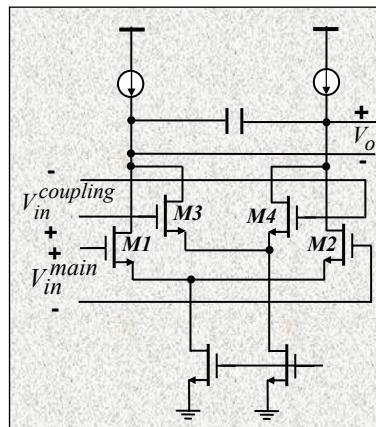
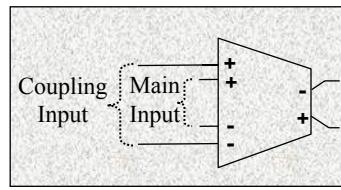
Coupling of resonators:

Use additional input source coupled pairs for the highlighted integrators  
For example, the middle integrator requires 3 sets of inputs

## Example: Coupling of the Resonators

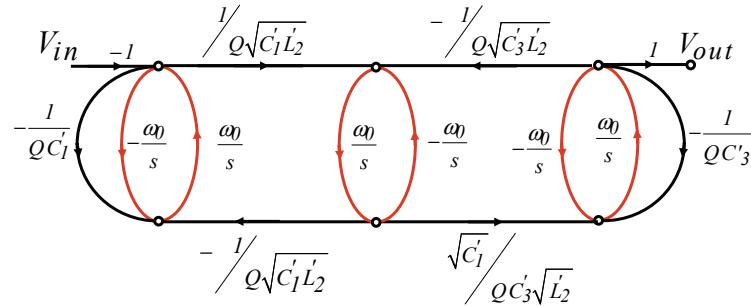
### 1- Additional Set of Input Devices

- Add one source couple pair for each additional input
- Coupling level  $\rightarrow$  ratio of device widths
- Disadvantage  $\rightarrow$  extra power dissipation



## Coupling of the Resonators

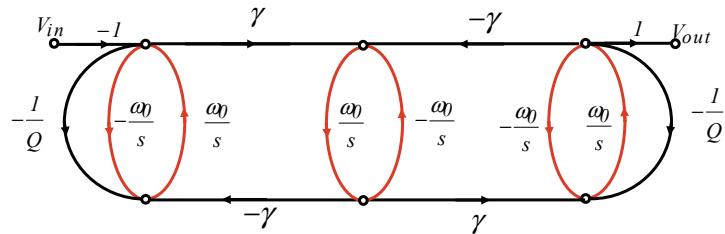
### 2- Modify SFG → Bidirectional Coupling Paths



Modified signal flowgraph to have equal coupling between resonators

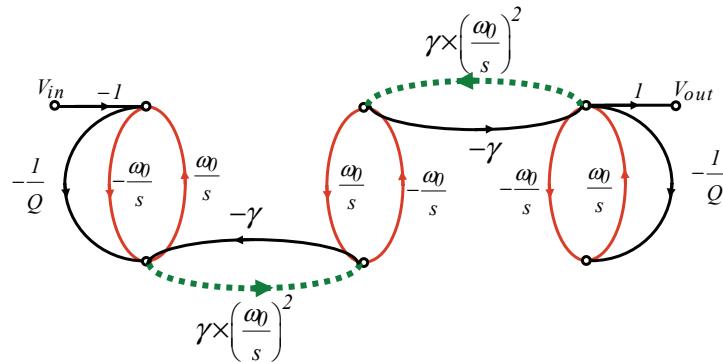
- In most filter cases  $C'_1 = C'_3$
- Example: For a butterworth lowpass filter  $C'_1 = C'_3 = I$  &  $L'_2 = 2$
- Assume desired overall bandpass filter  $Q = 10$

## Sixth Order Bandpass Filter Signal Flowgraph



- Where for a Butterworth shape  $\gamma = \frac{I}{Q\sqrt{2}}$
- Since in this example  $Q = 10$  then:  $\gamma \approx \frac{I}{14}$

## Sixth Order Bandpass Filter Signal Flowgraph SFG Modification



## Sixth Order Bandpass Filter Signal Flowgraph SFG Modification

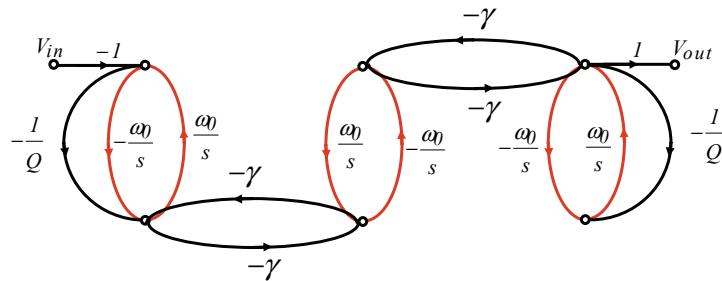
For narrow band filters (high Q) where frequencies within the passband are close to  $\omega_0$  *narrow-band approximation* can be used:

$$\text{Within filter passband: } \left(\frac{\omega_0}{\omega}\right)^2 \approx 1$$

$$\gamma \times \left(\frac{\omega_0}{s}\right)^2 = \gamma \times \left(\frac{\omega_0}{j\omega}\right)^2 \approx -\gamma$$

The resulting SFG:

## Sixth Order Bandpass Filter Signal Flowgraph SFG Modification



Bidirectional coupling paths, can easily be implemented with coupling capacitors → no extra power dissipation

## Sixth Order Gm-C Bandpass Filter Utilizing Simple Source-Coupled Pair Gm-Cell

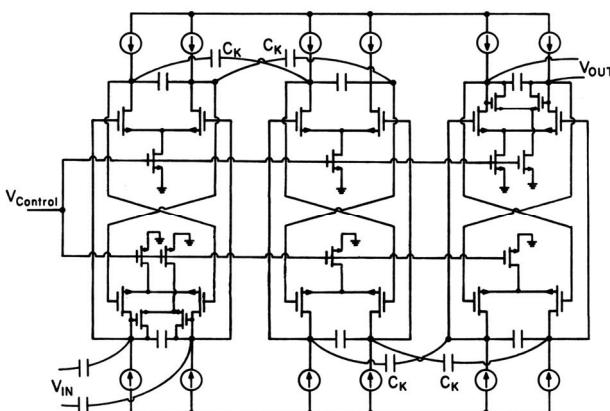
$$\gamma = \frac{C_k}{2 \times C_{int} g + C_k}$$

$$C_k = \frac{2 \times C_{int} g}{\frac{I}{\gamma} - I}$$

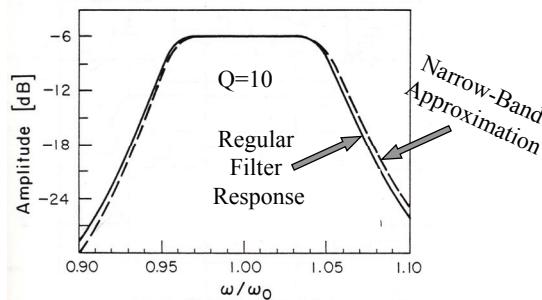
$$\gamma = I / 14$$

$$\rightarrow C_k = \frac{2}{13} C_{int} g$$

Parasitic cap. at integrator output, if unaccounted for, will result in inaccuracy in  $\gamma$



## Sixth Order Gm-C Bandpass Filter Narrow-Band versus Exact Frequency Response Simulation

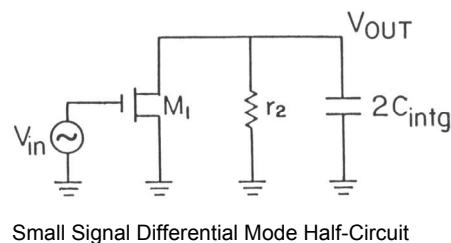


## Simplest Form of CMOS Gm-Cell Nonidealities

- DC gain (integrator Q)

$$a = \frac{g_m^{M1,2}}{g_0^{M1,2} + g_{load}}$$

$$a = \frac{2L}{\theta(V_{gs} - V_{th})_{M1,2}}$$



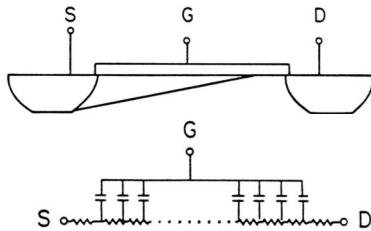
- Where  $a$  denotes DC gain &  $\theta$  is related to channel length modulation by:

$$\lambda = \frac{\theta}{L}$$

- Seems no extra poles!

## CMOS Gm-Cell High-Frequency Poles

Cross section view of a MOS transistor operating in saturation



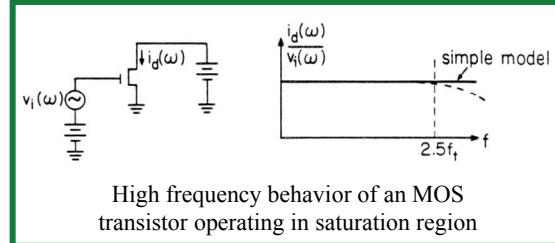
Distributed channel resistance & gate capacitance

- Distributed nature of gate capacitance & channel resistance results in infinite no. of high-frequency poles

## CMOS Gm-Cell High-Frequency Poles

$$P_2^{\text{effective}} \approx \frac{I}{\sum_{i=2}^{\infty} \frac{I}{P_i}}$$

$$P_2^{\text{effective}} \approx 2.5 \omega_t^{M1,2}$$



$$\omega_t^{M1,2} = \frac{g_m^{M1,2}}{2/3 C_{ox} WL} = \frac{3 \mu (V_{gs} - V_{th})_{M1,2}}{L^2}$$

- Distributed nature of gate capacitance & channel resistance results in an effective pole at 2.5 times input device cut-off frequency

## Simple Gm-Cell Quality Factor

$$a = \frac{2L}{\theta(V_{gs} - V_{th})_{M1,2}} \quad P_2^{\text{effective}} = \frac{15}{4} \frac{\mu(V_{gs} - V_{th})_{M1,2}}{L^2}$$

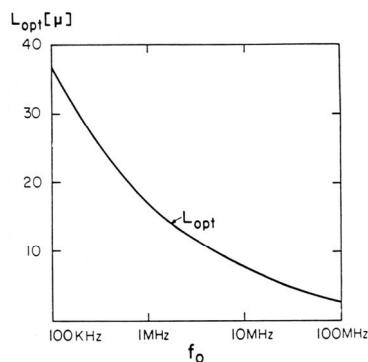
$$Q_{\text{real}}^{\text{intg.}} \approx \frac{1}{\frac{1}{a} - \omega_b \sum_{i=2}^{\infty} \frac{1}{p_i}}$$

$$\boxed{\frac{1}{Q^{\text{intg.}}} \approx \frac{\theta(V_{gs} - V_{th})_{M1,2}}{2L} - \frac{4}{15} \frac{\omega_b L^2}{\mu(V_{gs} - V_{th})_{M1,2}}}$$

- Note that phase lead associated with DC gain is inversely prop. to L
  - Phase lag due to high-freq. poles directly prop. to L
- For a given  $\omega_o$  there exists an optimum  $L$  which cancel the lead/lag phase error resulting in high integrator Q

## Simple Gm-Cell Channel Length for Optimum Integrator Quality Factor

$$L_{\text{opt.}} \approx \left[ \frac{15}{4} \frac{\theta \mu (V_{gs} - V_{th})_{M1,2}^2}{\omega_b} \right]^{1/3}$$

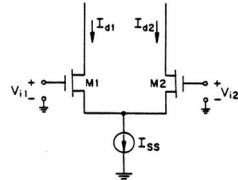


- Optimum channel length computed based on process parameters (could vary from process to process)

## Source-Coupled Pair CMOS Gm-Cell Transconductance

For a source-coupled pair the differential output current ( $\Delta I_d$ ) as a function of the input voltage ( $\Delta v_i$ ):

$$\Delta I_d = I_{ss} \left[ \frac{\Delta v_i}{(V_{gs} - V_{th})_{M1,2}} \right] \left\{ I - \frac{1}{4} \left[ \frac{\Delta v_i}{(V_{gs} - V_{th})_{M1,2}} \right]^2 \right\}^{1/2}$$

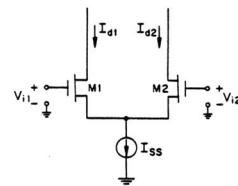
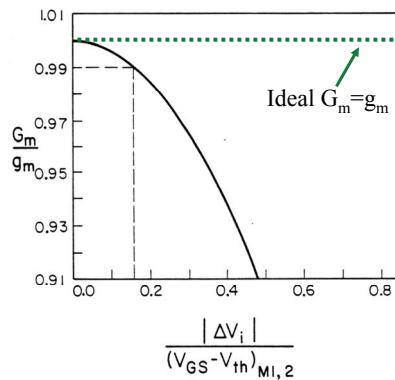


$$\text{Note: For small } \left[ \frac{\Delta v_i}{(V_{gs} - V_{th})_{M1,2}} \right] \rightarrow \frac{\Delta I_d}{\Delta v_i} = g_m^{M1,M2}$$

Note: As  $\Delta v_i$  increases  $\frac{\Delta I_d}{\Delta v_i}$  or the effective transconductance decreases

$$\Delta I_d = I_{d1} - I_{d2}$$

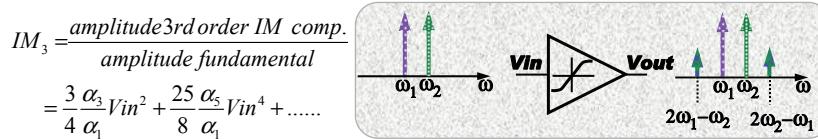
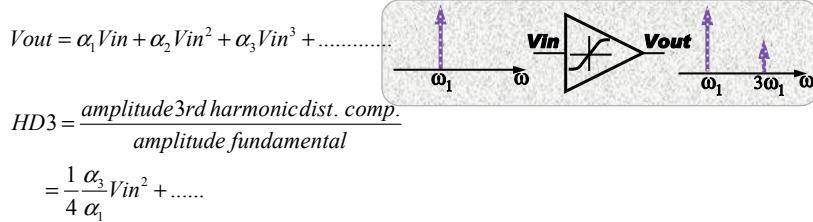
## Source-Coupled Pair CMOS Gm-Cell Linearity



$$\frac{|\Delta v_i|}{(V_{gs} - V_{th})_{M1,2}}$$

- Large signal  $G_m$  drops as input voltage increases  
→ Gives rise to nonlinearity

## Measure of Linearity



## Source-Coupled Pair Gm-Cell Linearity

$$\Delta I_d = I_{ss} \left[ \frac{\Delta v_i}{(V_{gs} - V_{th})_{M1,2}} \right] \left\{ 1 - \frac{1}{4} \left[ \frac{\Delta v_i}{(V_{gs} - V_{th})_{M1,2}} \right]^2 \right\}^{1/2} \quad (1)$$

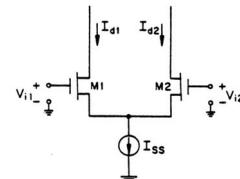
$$\Delta I_d = a_1 \times \Delta v_i + a_2 \times \Delta v_i^2 + a_3 \times \Delta v_i^3 + \dots$$

Series expansion used in (1)

$$a_1 = \frac{I_{ss}}{(V_{gs} - V_{th})_{M1,2}} \quad \& \quad a_2 = 0$$

$$a_3 = -\frac{I_{ss}}{8(V_{gs} - V_{th})_{M1,2}^3} \quad \& \quad a_4 = 0$$

$$a_5 = -\frac{I_{ss}}{128(V_{gs} - V_{th})_{M1,2}^5} \quad \& \quad a_6 = 0$$

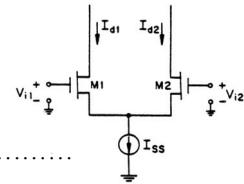


## Linearity of the Source-Coupled Pair CMOS Gm-Cell

$$IM_3 \approx \frac{3a_3}{4a_1} \hat{v}_i^2 + \frac{25a_5}{8a_1} \hat{v}_i^4 \dots \dots \dots$$

Substituting for  $a_1, a_3, \dots$

$$IM_3 \approx \frac{3}{32} \left( \frac{\hat{v}_i}{(V_{GS} - V_{th})} \right)^2 + \frac{25}{1024} \left( \frac{\hat{v}_i}{(V_{GS} - V_{th})} \right)^4 \dots \dots \dots$$



$$\hat{v}_{i\max} \approx 4(V_{GS} - V_{th}) \times \sqrt{\frac{2}{3} \times IM_3}$$

$$IM_3 = 1\% \text{ & } (V_{GS} - V_{th}) = 1V \Rightarrow \hat{v}_{in}^{rms} \approx 230mV$$

- Note that max. signal handling capability function of gate-overdrive voltage

## Simplest Form of CMOS Gm Cell Disadvantages

- Max. signal handling capability function of gate-overdrive

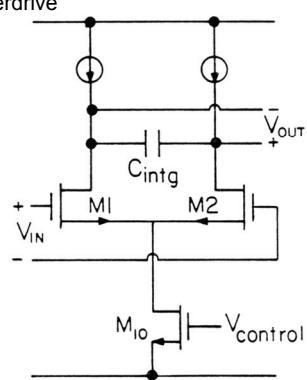
$$IM_3 \propto (V_{GS} - V_{th})^{-2}$$

- Critical freq. is also a function of gate-overdrive

$$\omega_o = \frac{g_m^{M1,2}}{2 \times C_{intg}}$$

$$\text{since } g_m = \mu C_{ox} \frac{W}{L} (V_{gs} - V_{th})$$

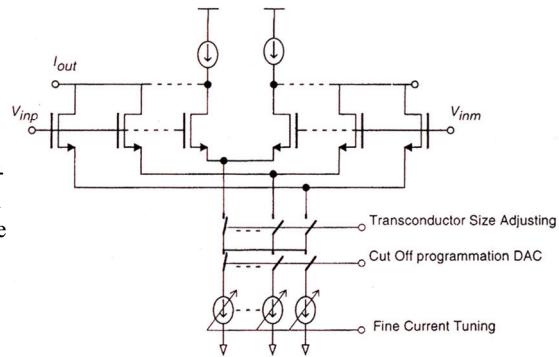
$$\text{then } \omega_o \propto (V_{gs} - V_{th})$$



→ Filter tuning affects max. signal handling capability!

## Simplest Form of CMOS Gm Cell Removing Dependence of Maximum Signal Handling Capability on Tuning

- Can overcome problem of max. signal handling capability being a function of tuning by providing tuning through :
  - Coarse tuning via switching in/out binary-weighted cross-coupled pairs → Try to keep gate overdrive voltage constant
  - Fine tuning through varying current sources



→ Dynamic range dependence on tuning removed (to 1<sup>st</sup> order)

Ref: R.Castello ,I.Bietti, F. Svelto , "High-Frequency Analog Filters in Deep Submicron Technology ,  
"International Solid State Circuits Conference, pp 74-75, 1999.

## Dynamic Range for Source-Coupled Pair Based Filter

$$IM_3 = 1\% \quad \& \quad (V_{GS} - V_{th}) = 1V \Rightarrow V_{in}^{rms} \approx 230mV$$

- Minimum detectable signal determined by total noise voltage
- It can be shown for the 6<sup>th</sup> order Butterworth bandpass filter fundamental noise contribution is given by:

$$\sqrt{v_o^2} \approx \sqrt{3Q \frac{kT}{C_{intg}}}$$

$$Assuming \quad Q=10 \quad C_{intg}=5pF$$

$$v_{noise}^{rms} \approx 160\mu V$$

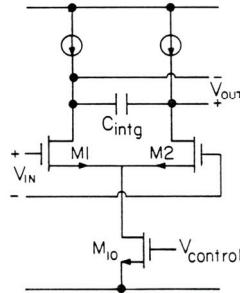
$$since \quad v_{max}^{rms} = 230mV$$

$$Dynamic Range = 20 \log \frac{230 \times 10^{-3}}{160 \times 10^{-6}} \approx 63dB$$

## Simplest Form of CMOS Gm-Cell

- Pros
  - Capable of very high frequency performance (highest?)
  - Simple design
- Cons
  - Tuning affects max. signal handling capability (can overcome)
  - Limited linearity (possible to improve)
  - Tuning affects power dissipation

Ref: H. Khorramabadi and P.R. Gray, "High Frequency CMOS continuous-time filters," *IEEE Journal of Solid-State Circuits*, Vol.-SC-19, No. 6, pp.939-948, Dec. 1984.



## Gm-Cell Source-Coupled Pair with Degeneration

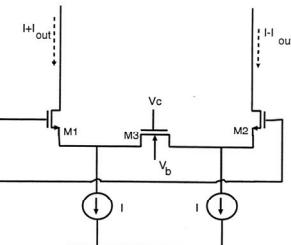
$$I_d = \frac{\mu C_{ox}}{2} \frac{W}{L} \left[ 2(V_{gs} - V_{th})V_{ds} - V_{ds}^2 \right]$$

$$g_{ds} = \frac{\partial I_d}{\partial V_{ds}} \approx \mu C_{ox} \frac{W}{L} (V_{gs} - V_{th}) \Big|_{V_{ds} \text{ small}}$$

$$g_{eff} = \frac{I}{\frac{1}{M3} + \frac{2}{g_m^{MI,2}}}$$

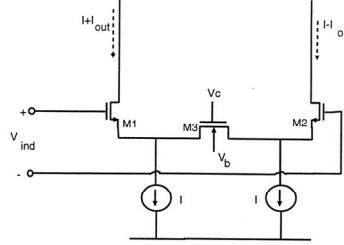
for  $g_m^{MI,2} \gg g_{ds}^{M3}$

$$g_{eff} \approx g_{ds}^{M3}$$



M3 operating in triode mode → source degeneration → determines overall gm  
Provides tuning through varing Vc (DC voltage source)

## Gm-Cell Source-Coupled Pair with Degeneration



- Pros

- Moderate linearity
- Continuous tuning provided by varying  $V_c$
- Tuning does not affect power dissipation

- Cons

- Extra poles associated with the source of M1,2,3  
→ Low frequency applications only

Ref: Y. Tsividis, Z. Czarnul and S.C. Fang, "MOS transconductors and integrators with high linearity," *Electronics Letters*, vol. 22, pp. 245-246, Feb. 27, 1986

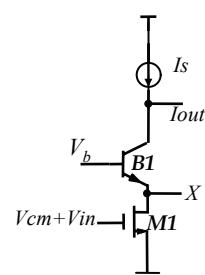
## BiCMOS Gm-Cell Example

- MOSFET in triode mode (M1):

$$I_d = \frac{\mu C_{ox} W}{2 L} [2(V_{gs} - V_{th})V_{ds} - V_{ds}^2]$$

$$g_m^{MI} = \frac{\partial I_d}{\partial V_{gs}} = \mu C_{ox} \frac{W}{L} V_{ds}$$

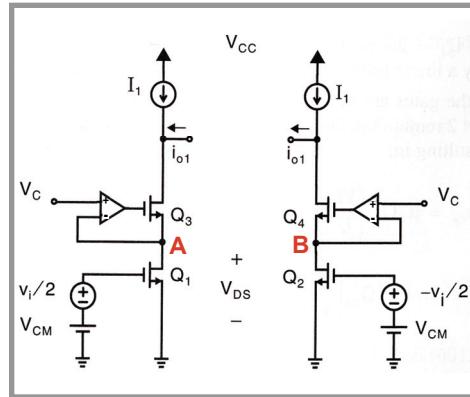
- Note that if  $V_{ds}$  is kept constant →  $g_m$  stays constant
- Linearity performance → keep  $g_m$  constant as  $V_{in}$  varies → function of how constant  $V_{ds}^{MI}$  can be held
  - Need to minimize Gain @ Node X
- Since for a given current,  $g_m$  of BJT is larger compared to MOS- preferable to use BJT
- Extra pole at node X could limit max. freq.



Varying  $V_b$  changes  $V_{ds}^{MI}$   
→ adjustable overall stage  $g_m$

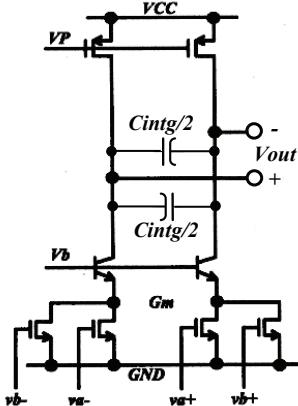
## Alternative Fully CMOS Gm-Cell Example

- BJT replaced by a MOS transistor with boosted  $g_m$
- Lower frequency of operation compared to the BiCMOS version due to more parasitic capacitance at nodes A & B

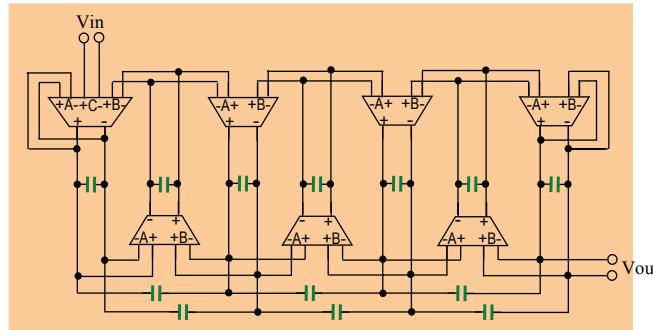


## BiCMOS Gm-C Integrator

- Differential- needs common-mode feedback ckt
- Freq.tuned by varying  $V_b$
- Design tradeoffs:
  - Extra poles at the input device drain junctions
  - Input devices have to be small to minimize parasitic poles
  - Results in high input-referred offset voltage → could drive ckt into non-linear region
  - Small devices → high 1/f noise



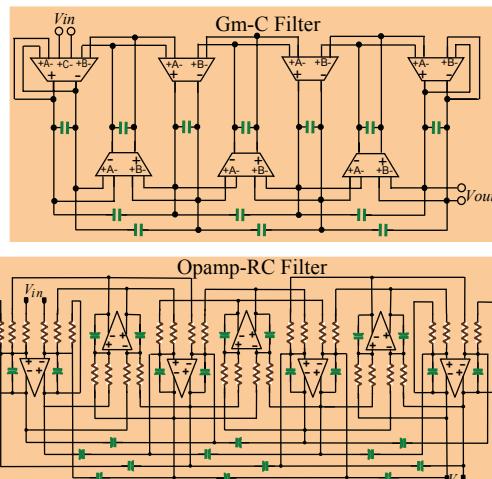
## 7<sup>th</sup> Order Elliptic Gm-C LPF For CDMA RX Baseband Application



- Gm-Cell in previous page used to build a 7th order elliptic filter for CDMA baseband applications (625kHz corner frequency)
- In-band dynamic range of <50dB achieved

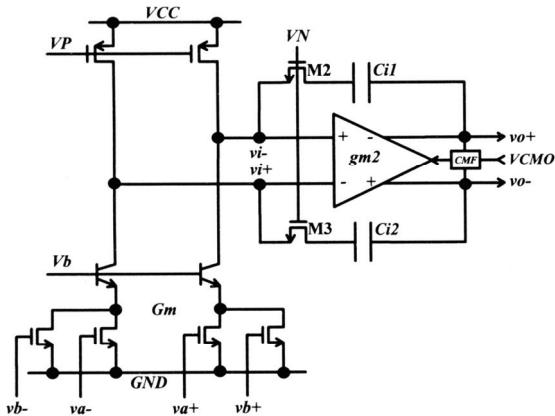
## Comparison of 7<sup>th</sup> Order Gm-C versus Opamp-RC LPF

- Gm-C filter requires 4 times less intg. cap. area compared to Opamp-RC  
→ For low-noise applications where filter area is dominated by  $C_s$ , could make a significant difference in the total area
- Opamp-RC linearity superior compared to Gm-C
- Power dissipation tends to be lower for Gm-C since OTA load is  $C$  and thus no need for buffering



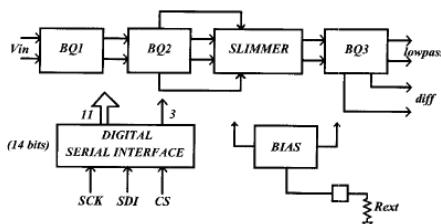
## BiCMOS Gm-OTA-C Integrator

- Used to build filter for disk-drive applications
- Since high frequency of operation, time-constant sensitivity to parasitic caps significant.  
→ Opamp used
- M2 & M3 added to compensate for phase lag (provides phase lead)



**Ref:** C. Laber and P. Gray, "A 20MHz 6th Order BiCMOS Parasitic Insensitive Continuous-time Filter & Second Order Equalizer Optimized for Disk Drive Read Channels," *IEEE Journal of Solid State Circuits*, Vol. 28, pp. 462-470, April 1993.

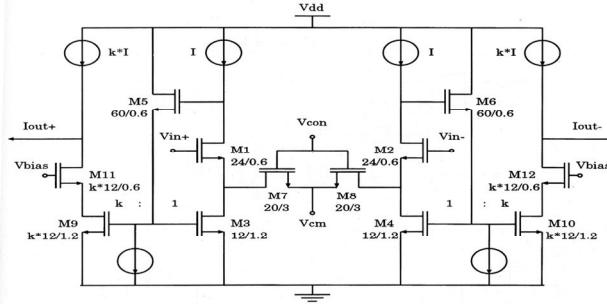
## 6th Order BiCMOS Continuous-time Filter & Second Order Equalizer for Disk Drive Read Channels



- Gm-C-opamp of the previous page used to build a 6<sup>th</sup> order filter for Disk Drive
- Filter consists of cascade of 3 biquads with max. Q of 2 each
- Performance in the order of 40dB SNDR achieved for up to 20MHz corner frequency

**Ref:** C. Laber and P. Gray, "A 20MHz 6th Order BiCMOS Parasitic Insensitive Continuous-time Filter & Second Order Equalizer Optimized for Disk Drive Read Channels," *IEEE Journal of Solid State Circuits*, Vol. 28, pp. 462-470, April 1993.

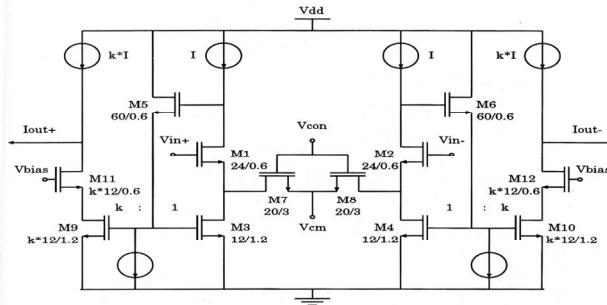
## Gm-Cell Source-Coupled Pair with Degeneration



- Gm-cell intended for low Q disk drive filter
- M7,8 operating in triode mode provide source degeneration for M1,2  
→ determine the overall  $g_m$  of the cell

Ref: I.Mehr and D.R.Welland, "A CMOS Continuous-Time Gm-C Filter for PRML Read Channel Applications at 150 Mb/s and Beyond", IEEE Journal of Solid-State Circuits, April 1997, Vol.32, No.4, pp. 499-513.

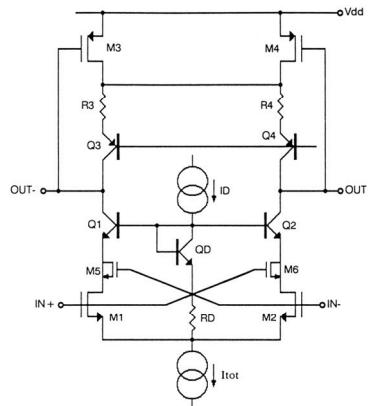
## Gm-Cell Source-Coupled Pair with Degeneration



- Feedback provided by M5,6 maintains the gate-source voltage of M1,2 constant by forcing their current to be constant → helps deliver  $V_{in}$  across M7,8 with good linearity
- Current mirrored to the output via M9,10 with a factor of  $k$  → overall  $gm$  scaled by  $k$
- Performance level of about 50dB SNDR at  $f_{corner}$  of 25MHz achieved

## BiCMOS Gm-C Integrator

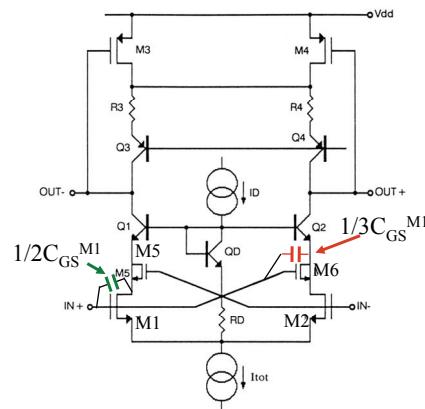
- Needs higher supply voltage compared to the previous design since quite a few devices are stacked vertically
- M1,2 → triode mode
- Q1,2 → hold  $V_{ds}$  of M1,2 constant
- Current ID used to tune filter critical frequency by varying  $V_{ds}$  of M1,2 and thus controlling  $gm$  of M1,2
- M3, M4 operate in triode mode and added to provide common-mode feedback



**Ref:** R. Alini, A. Baschirotto, and R. Castello, "Tunable BiCMOS Continuous-Time Filter for High-Frequency Applications," *IEEE Journal of Solid State Circuits*, Vol. 27, No. 12, pp. 1905-1915, Dec. 1992.

## BiCMOS Gm-C Integrator

- M5 & M6 configured as capacitors- added to compensate for RHP zero due to  $C_{gd}$  of M1,2 (moves it to LHP) size of M5,6 →  $1/3$  of M1,2



**Ref:** R. Alini, A. Baschirotto, and R. Castello, "Tunable BiCMOS Continuous-Time Filter for High-Frequency Applications," *IEEE Journal of Solid State Circuits*, Vol. 27, No. 12, pp. 1905-1915, Dec. 1992.